

Features

- Error Detection mode to detect individual LED open-circuit errors
- I 8 constant-current output channels
- I Constant output current invariant to load voltage change
- Excellent output current accuracy: between channels: < ±4% (max.), and between ICs: < ±6% (max.)
- I Output current adjusted through an external resistor
- I Constant output current range: 5 -120 mA
- Fast response of output current, \overline{OE} (min.): 400 ns
- I 25MHz clock frequency
- I Schmitt trigger input
- I 5V supply voltage



Current	Accuracy	Conditions			
Between Channels Between ICs		Conditions			
< ±4% < ±6%		I_{OUT} = 10 mA to 60 mA, V_{DS} = 0.6V			
< ±6%	< ±12%	I_{OUT} = 60 mA to100 mA, V_{DS} = 0.8V			

Product Description

MBI5169 succeeds MBI5168 and is designed for LED displays with open-circuit Error Detection extension. MBI5169 exploits PrecisionDrive[™] technology to enhance its output characteristics. MBI5169 contains a serial buffer and data latches, which convert serial input data into parallel output format. At MBI5169 output stage, eight regulated current ports are designed to provide uniform and constant current sinks for driving LEDs within a wide range of Vf variations.

While MBI5169 is used in their system design for LED display applications, e.g. LED panels, it provides users with great flexibility and device performance. Users may adjust the output current from 5 mA to 120 mA through an external resistor, R_{ext}, which gives users flexibility in controlling the light intensity of LEDs. MBI5169 guarantees to endure maximum 17V at the output port. The high clock frequency, 25 MHz, also satisfies the system requirements of high volume data transmission.

MBI5169 exploits the idea of Share-I-O[™] technology to extend its performance ; in addition, MBI5169 is backward compatible with MBI5168 in both electrical characteristics and package aspect. With Share-I-O[™] technology, users can, without changing the printed circuit board originally for MBI5168, let MBI5169 enter a special function mode, an Error Detection mode, just by setting a sequence of signals on LE(ED1), \overline{OE} (ED2) and CLK input pins. In the Error Detection mode, MBI5169 detects the status of individual LED connected to MBI5169. The status will be saved in a built-in register. Then, a system controller may read, through SDO pin, the error status from the register to know whether LEDs are properly lit or not. By setting another sequence of signals on LE(ED1), \overline{OE} (ED2) and CLK input pins, MBI5169 may resume to a Normal mode and perform as MBI5168. In **Application Information**, users can get detailed ideas about how MBI5169 works in the Error Detection mode.

A Share-I-O[™] technique is specifically applied to MBI5169. By means of the Share-I-O[™] technique, an additionally effective function, Error Detection, can be added to LED drivers, however, without any extra pins. Thus, MBI5169 could be a drop-in replacement of MBI5168. The printed circuit board originally designed for MBI5168 may be also applicable for MBI5169.

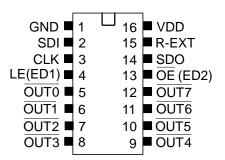
For MBI5169, the pin 4, LE(ED1), and the pin 13, \overline{OE} (ED2), can be acted as different functions as follows:

Pin Device Name	MBI5169
Function Description of Pin 4	LE + Error Detection (ED1)
Function Description of Pin 13	OE + Error Detection (ED2)

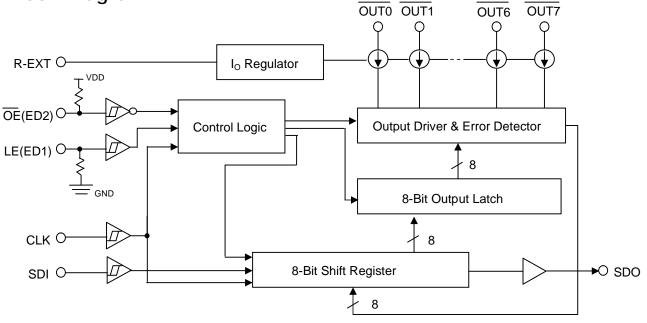
Terminal Description

PIN NO.	PIN NAME	FUNCTION
1	GND	Ground terminal for control logic and current sink
2	SDI	Serial-data input to the Shift Register
3	CLK	Clock input terminal for data shift on rising edge
		Data strobe input terminal
4	LE(ED1)	Serial data is transferred to the respective latch when LE(ED1) is high. The data is latched when LE(ED1) goes low.
		Also, a control signal input for Error Detection mode (See Timing Diagram)
5-12	$\overline{OUT0} \sim \overline{OUT7}$	Constant current output terminals
13	OE (ED2)	Output enable terminal When (active) low, the output drivers are enabled; when high, all output drivers are turned OFF (blanked). Also, a control signal input for Error Detection mode (See Timing Diagram)
14	SDO	Serial-data output to the following SDI of next driver IC
15	R-EXT	Input terminal used to connect an external resistor for setting up all output current
16	VDD	5V supply voltage terminal

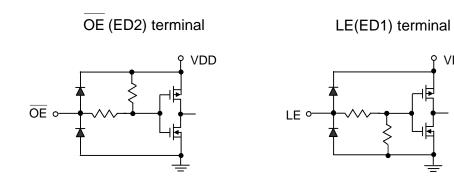
Pin Description



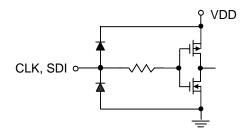
Block Diagram



Equivalent Circuits of Inputs and Outputs

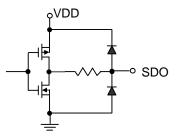






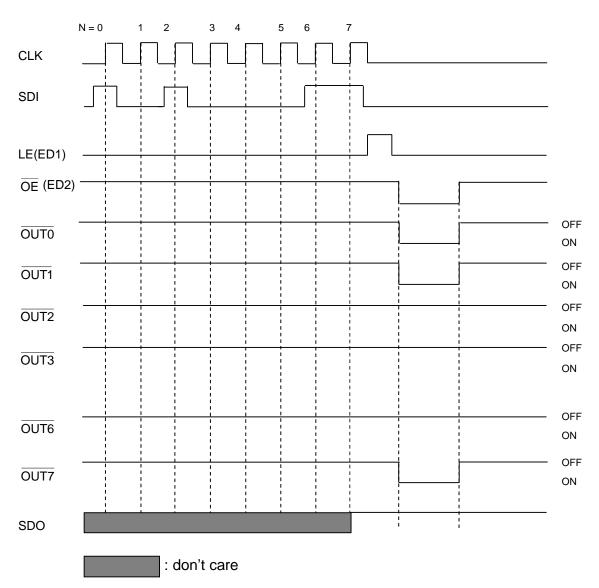
SDO terminal

VDD



Timing Diagram

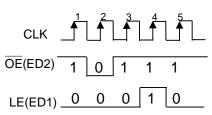
Normal Mode



Truth Table (In Normal Mode)

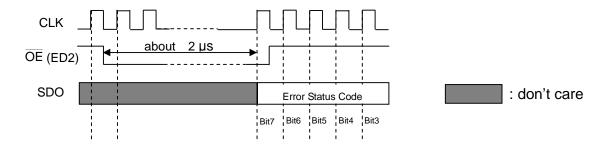
CLK	LE	OE	SDI	OUT0 OUT5 OUT 7	SDO
	Н	L	D _n	$\overline{Dn} \dots \overline{Dn \cdot 5} \dots \overline{Dn \cdot 7}$	D _{n-7}
	L	L	D _{n+1}	No Change	D _{n-6}
	Н	L	D _{n+2}	$\overline{Dn+2}$ $\overline{Dn-3}$ $\overline{Dn-5}$	D _{n-5}
· ↓	Х	L	D _{n+3}	Dn+2 Dn-3 Dn-5	D _{n-5}
_	х	Н	D _{n+3}	Off	D _{n-5}

Entering Error Detection Mode



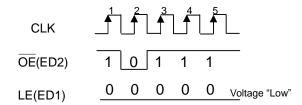
The signal sequence makes MBI5169 enter an Error Detection mode.

Reading Error Status Code



A system controller can read Error Status codes through SDO pin.

Resuming to Normal Mode



The signal sequence makes MBI5169 resume to the Normal mode.

Note:

If users want to know the whole process, that is how to enter the Error Detection mode, read Error Status codes and resume to the Normal mode, please refer to the contents in **Application Information**.

Maximum Ratings

CHARACTE	RISTIC	SYMBOL	RATING	UNIT	
Supply Voltage		V _{DD}	0~7.0	V	
Input Voltage		V _{IN}	-0.4~V _{DD} + 0.4	V	
Output Current		I _{OUT}	+120	mA	
Output Voltage		V _{DS}	-0.5~+20.0	V	
Clock Frequency		F _{CLK}	25	MHz	
GND Terminal Current		I _{GND}	960	mA	
	CN – type		1.64		
Power Dissipation (On PCB, Ta=25°C)	CD – type	P _D	1.06	W	
(011 00, 10-20 0)	CP – type		0.88		
	CN – type		76		
Thermal Resistance (On PCB, Ta=25°C) CD – type		R _{th(j-a)}	117	°C/W	
(011 00, 10-20 0)	CP – type		141		
Operating Temperature		T _{opr}	-40~+85	°C	
Storage Temperature		T _{stg}	-55~+150	°C	

Recommended Operating Conditions

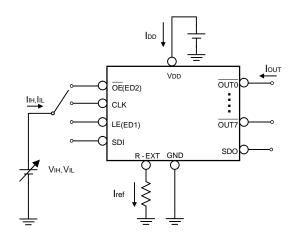
Characteristic	Symbol	Condition	Min.	Тур.	Max.	Unit
Supply Voltage	V _{DD}	-	4.5	5.0	5.5	V
Output Voltage	V _{DS}	OUT0 ~ OUT7	-	-	17.0	V
	I _{OUT}	DC Test Circuit	5	-	120	mA
Output Current	I _{он}	SDO	-	-	-1.0	mA
	I _{OL}	SDO	-	-	1.0	mA
Input Voltage	V _{IH}	CLK, OE (ED2), LE(ED1) and SDI	0.8V _{DD}	-	V _{DD} +0.3	V
input voltage	V _{IL}	CLK, OE (ED2), LE(ED1) and SDI	-0.3	-	$0.3V_{DD}$	V
LE(ED1) Pulse Width	t _{w(L)}		40	-	-	ns
CLK Pulse Width	t _{w(CLK)}		20	-	-	ns
OE (ED2) Pulse Width	t _{w(OE)}		400	-	-	ns
Setup Time for SDI	t _{su(D)}	Normal Mode V _{DD} =4.5~5.5V	5	-	-	ns
Hold Time for SDI	t _{h(D)}		10	-	-	ns
Setup Time for LE(ED1)	t _{su(L)}		15	-	-	ns
Hold Time for LE(ED1)	t _{h(L)}		15	-	-	ns
OE (ED2) Pulse Width	t _{w(ED2)}		2	-	-	μs
CLK Pulse Width	t _{w(CLK)}		20	-	-	ns
Setup Time for LE(ED1)	t _{su(ED1)}	Error Detection Mode	5	-	-	ns
Hold Time for LE(ED1)	t _{h(ED1)}	V _{DD} =4.5~5.5V	10	-	-	ns
Setup Time for \overline{OE} (ED2)	t _{su(ED2)}		5	-	-	ns
Hold Time for OE (ED2)	t _{h(ED2)}		10	-	-	ns
Clock Frequency	F _{CLK}	Cascade Operation	-	-	25.0	MHz
			-	-	0.85	
Power Dissipation	P _D	Ta=85°C	-	-	0.55	W
			-	-	0.46	

Electrical Characteristics

CHARACTERISTIC		SYMBOL	CONDITION		MIN.	TYP.	MAX.	UNIT
	"H" level	V _{IH}	Ta = -40~85°C		0.8V _{DD}	-	V _{DD}	V
Input Voltage	"L" level	V _{IL}	Ta = -4	0~85°C	GND	-	$0.3V_{DD}$	V
Output Leak	age Current	I _{OH}	V _{OH} =	17.0V	-	-	0.5	μA
Output Voltage	e SDO	V _{OL}	I _{OL} =+1.0mA		-	I	0.4	V
	500	V _{OH}	I _{OH} =-′	1.0mA	4.6	·	-	V
Output C	Current 1	I _{OUT1}	V _{DS} =0.6V	R _{ext} =744 Ω	-	25.0	-	mA
Curren	t Skew	dl _{OUT1}	I _{OUT} =25mA V _{DS} =0.6V	R _{ext} =744 Ω	-	±1	±4	%
Output C	Current 2	I _{OUT2}	V _{DS} =0.6V	R _{ext} =372 Ω	-	50.0	-	mA
Curren	t Skew	dl _{OUT2}	I _{OUT} =50mA V _{DS} =0.6V	R _{ext} =372 Ω	-	±1	±4	%
Output C	Current 3	I _{OUT3}	V _{DS} =0.8V	R _{ext} =186 Ω	-	100	-	mA
Current Skew		dl _{OUT3}	I _{OUT} =100mA V _{DS} =0.8V	R _{ext} =186 Ω	-	±1	±6	%
Output Current vs. Output Voltage Regulation		%/dV _{DS}	V_{DS} within 1.0V and 3.0V		-	±0.1	-	% / V
Output Curren Supply Voltage		%/dV _{DD}	V_{DD} within 4.5V and 5.5V		-	±1	-	% / V
Pull-up Resis	stor	R _{IN} (up)	OE (ED2)	250	500	800	KΩ
Pull-down Re	esistor	R _{IN} (down)	LE(ED1)		250	500	800	KΩ
		$V_{\text{DS, Th1}}$	When all output ports sink 20mA simultaneously		TBD	-	-	V
Open Circ	cuit Error***	$V_{\text{DS}, \text{Th2}}$	When a single output port sinks 20mA		TBD	-	-	V
Discriminat	ion Voltage	V _{DS, Th3}	When all output ports sink 50mA simultaneously		TBD	-	-	V
		V _{DS, Th4}	When a single ou 50mA	TBD	-	-	V	
		I _{DD} (off) 1	R_{ext} =Open, $\overline{OUT0} \sim \overline{OUT7}$ =Off R_{ext} =744 Ω , $\overline{OUT0} \sim \overline{OUT7}$ =Off		-	9	-	
	"OFF"	I _{DD} (off) 2			-	10	-	
Supply Current		I _{DD} (off) 3	R _{ext} =372 Ω, <u>ου</u>	TTO ~ OUT7 =Off	-	11	-	mA
	"ON"	I _{DD} (on) 1	$R_{ext}=744 \Omega, \overline{OUT0} \sim \overline{OUT7} = On$		-	10	-	
		I _{DD} (on) 2	$R_{ext}=372 \Omega, \overline{OU}$	TTO ~ OUT7 =On	-	11	-	

*** To effectively detect the error occurring at the output port, MBI5169 has a built-in current detection circuit. The current detection circuit will detect the effective current $I_{OUT, effective}$, and compare the effective current $I_{OUT, effective}$, to the target current $I_{OUT, target}$, defined by R_{ext} . If $I_{OUT, effective}$, is much less than the target current $I_{OUT, target}$, an error flag will be asserted in the built-in Shift Register. The minimum voltage requirement for such current detection is $V_{DS, Th1}$, $V_{DS, Th2}$, $V_{DS, Th3}$ and $V_{DS, Th4}$.

Test Circuit for Electrical Characteristics

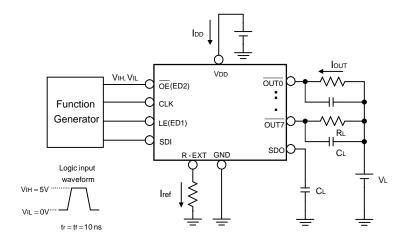


CHARACTERISTIC		SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
	CLK - OUTn	t _{pLH1}		-	50	100	ns
Propagation Delay Time	LE(ED1) - OUTn	t _{pLH2}		-	50	100	ns
("L" to "H")	OE (ED2) - OUTn	t _{pLH3}		-	20	100	ns
	CLK - SDO	t _{pLH}		15	20	-	ns
	CLK - OUTn	t _{pHL1}	V _{DD} =5.0 V V _{DS} =0.8 V	-	100	150	ns
Propagation Delay Time	LE(ED1) - OUTn	t _{pHL2}	V _{IH} =V _{DD}	-	100	150	ns
("H" to "L")	OE (ED2) - OUTn	t _{pHL3}	V _{IL} =GND R _{ext} =366 Ω	-	50	150	ns
	CLK - SDO	t _{pHL}	V _L =4.0 V R _L =52 Ω	15	20	-	ns
	CLK	$t_{w(CLK)}$	κ _L =32 Ω C _L =10 pF	20	-	-	ns
Pulse Width	LE(ED1)	t _{w(L)}		20	-	-	ns
	OE (ED2)	$t_{w(OE)}$		400	-	-	ns
Hold Time for L	E(ED1)	t _{h(L)}		5	-	-	ns
Setup Time for	Setup Time for LE(ED1)			5	-	-	ns
Maximum CLK Rise Time		t _r **		-	-	500	ns
Maximum CLK Fall Time		t _f **		-	-	500	ns
Output Rise Time of lout		t _{or}		-	70	200	ns
Output Fall Tim	e of lout	t _{of}		-	40	120	ns

Switching Characteristics

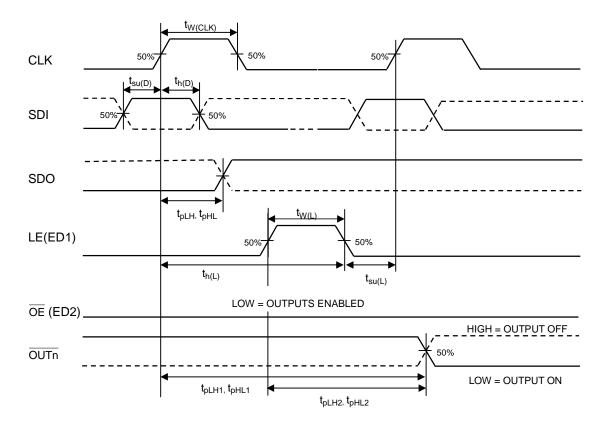
**If the devices are connected in cascade and t_r or t_f is large, it may be critical to achieve the timing required for data transfer between two cascaded devices.

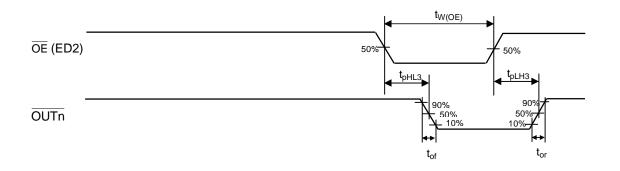
Test Circuit for Switching Characteristics

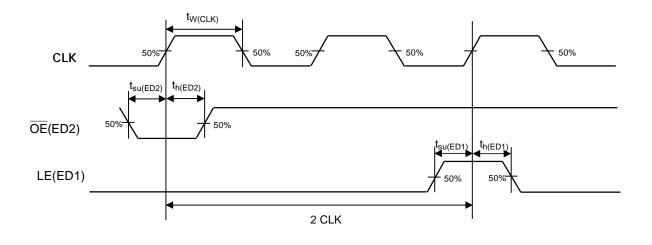


Timing Waveform

Normal Mode

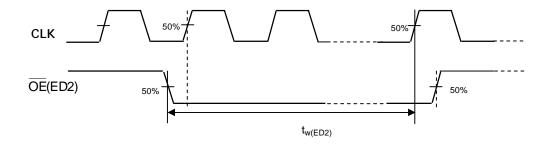






Entering Error Detection Mode

Reading Error Status Code



Application Information

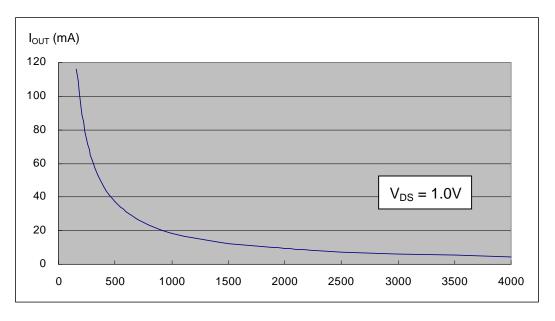
Constant Current

To design LED displays, MBI5168 provides nearly no variations in current from channel to channel and from IC to IC. This can be achieved by:

- 1) While $I_{OUT} \leq 60$ mA, the maximum current variation between channels is less than ±4%, and that between ICs is less than ±6%.
- 2) In addition, the current characteristic of output stage is flat and users can refer to the figure as shown below. The output current can be kept constant regardless of the variations of LED forward voltages (Vf). This performs as a perfection of load regulation.

Adjusting Output Current

The output current of each channel (I_{OUT}) is set by an external resistor, R_{ext} . The relationship between I_{out} and R_{ext} is shown in the following figure.



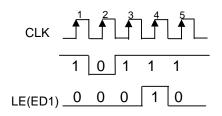


Also, the output current in milliamps can be calculated from the equation:

I_{OUT} is (620 / R_{ext}) x 30, approximately,

where R_{ext} , in Ω , is the resistance of the external resistor connected to R-EXT terminal. The magnitude of current (as a function of R_{ext}) is around 50mA at 372 Ω and 25mA at 744 Ω .

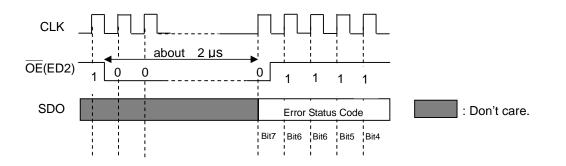
Entering Error Detection Mode



Each time the system controller sends the sequence patterns shown above, MBI5169 can enter the Error Detection mode. During this phase, the system controller can still send data through SDI pin.

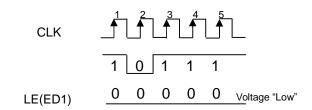
The state of \overline{OE} (ED2) and LE(ED1) is sampled by the rising edge of each CLK. We use "0" and "1" to represent the state of "Voltage Low" and "Voltage High" respectively. The states of the successive five \overline{OE} (ED2) and LE(ED1) are (1, 0), (0, 0), (1, 0), (1, 1) and (1, 0).

Reading Error Status Code



Once entering the Error Detection mode, the Error Detection takes place by changing the state of \overline{OE} (ED2) from "Voltage High" to "Voltage Low". The built-in current detection circuit will detect the effective current $I_{OUT, effective}$ of each output channel, and compare it to the target current $I_{OUT, target}$, defined by R_{ext} . If the $I_{OUT, effective}$, is much less than the target current $I_{OUT, target}$, an error status code will be represented as "0" state. During the period of detecting errors, data cannot be sent into MBI5169 through SDI pin. The "Voltage Low" state of \overline{OE} (ED2) requires at least three "0" of which the last "0" should be at least 2µs after the falling edge of \overline{OE} (ED2). The occurrence of the last "0" results in the event that MBI5169 saves the error status in the built-in register. The mentioned state of each "0" is sampled by the rising edge of each CLK. Before the error status saved in the built-in register is read, the state of \overline{OE} (ED2) should be pulled up from "Voltage Low" to "Voltage High". Then, by sending CLK, MBI5169 shifts out, through SDO pin, the error status bit by bit.

Resuming to Normal Mode

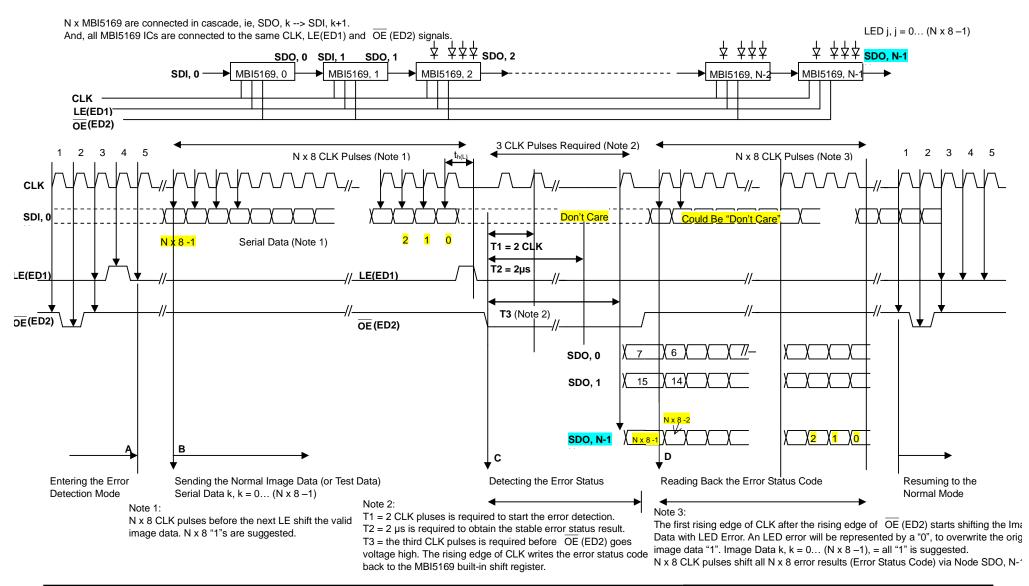


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<u>MBI5169</u>

Timing Chart for Error Detection Mode (An Example)



Package Power Dissipation (P_D)

The maximum allowable package power dissipation is determined as $P_D(max) = (Tj - Ta) / R_{th(j-a)}$. When 8 output channels are turned on simultaneously, the actual package power dissipation is $P_D(act) = (I_{DD} \times V_{DD}) + (I_{OUT} \times Duty \times V_{DS} \times 8)$. Therefore, to keep $P_D(act) \le P_D(max)$, the allowable maximum output current as a function of duty cycle is:

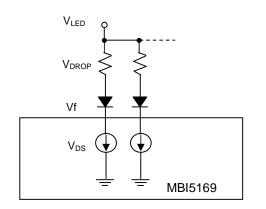
 $I_{OUT} = \{ \ [\ (Tj - Ta) \ / \ R_{th(j-a)} \] - (I_{DD} \ x \ V_{DD}) \ \} \ / \ V_{DS} \ / \ Duty \ / \ 8, \label{eq:IOUT}$ where $Tj = 150^{\circ}C.$

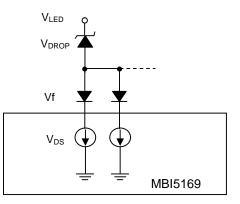
Load Supply Voltage (V_{LED})

MBI5168 are designed to operate with V_{DS} ranging from 0.4V to 1.0V considering the package power dissipating limits. V_{DS} may be higher enough to make $P_{D(act)} > P_{D(max)}$ when $V_{LED} = 5V$ and $V_{DS} = V_{LED} - Vf$. In this case, it is recommended to use the lowest possible supply voltage or to set an external voltage reducer, V_{DROP} .

A voltage reducer lets $V_{DS} = (V_{LED} - Vf) - V_{DROP}$.

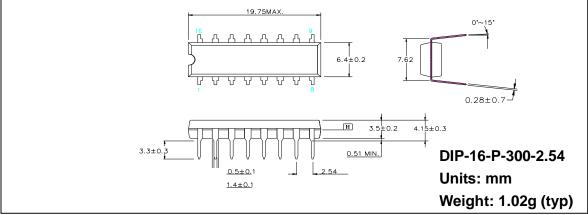
Resistors or Zener diode can be used in the applications as shown in the following figures.



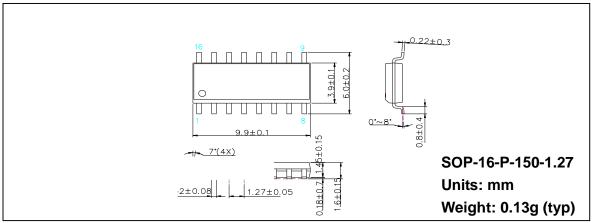


Outline Drawings

<u>MBI5169CN</u>



MBI5169CD



MBI5169CP

